

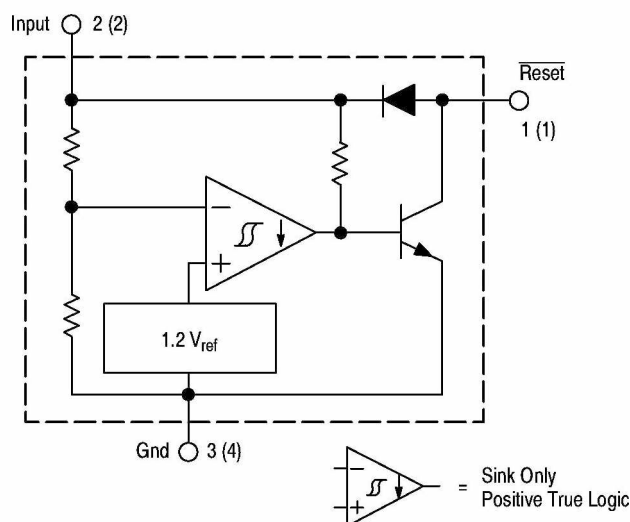
MC34164, MC33164

Micropower Undervoltage Sensing Circuits

The MC34164 series are undervoltage sensing circuits specifically designed for use as reset controllers in portable microprocessor based systems where extended battery life is required. These devices offer the designer an economical solution for low voltage detection with a single external resistor. The MC34164 series features a bandgap reference, a comparator with precise thresholds and built-in hysteresis to prevent erratic reset operation, an open collector reset output capable of sinking in excess of 6.0 mA, and guaranteed operation down to 1.0 V input with extremely low standby current. These devices are packaged in 3-pin TO-226AA, 8-pin SO-8 and Micro8™ surface mount packages.

Applications include direct monitoring of the 3.0 or 5.0 V MPU/logic power supply used in appliance, automotive, consumer, and industrial equipment.

- Temperature Compensated Reference
- Monitors 3.0 V (MC34164-3) or 5.0 V (MC34164-5) Power Supplies
- Precise Comparator Thresholds Guaranteed Over Temperature
- Comparator Hysteresis Prevents Erratic Reset
- Reset Output Capable of Sinking in Excess of 6.0 mA
- Internal Clamp Diode for Discharging Delay Capacitor
- Guaranteed Reset Operation With 1.0 V Input
- Extremely Low Standby Current: As Low as 9.0 μ A
- Economical TO-226AA, SO-8 and Micro8 Surface Mount Packages



Pin numbers adjacent to terminals are for the 3-pin TO-226AA package.
Pin numbers in parenthesis are for the 8-lead packages.

This device contains 28 active transistors.

Figure 1. Representative Block Diagram



ON Semiconductor

<http://onsemi.com>



**TO-226AA
P SUFFIX
CASE 29**

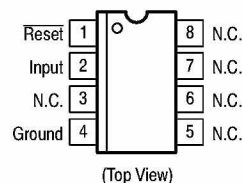


**SO-8
D SUFFIX
CASE 751**



**Micro8
DM SUFFIX
CASE 846A**

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2771 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 2771 of this data sheet.

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MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Input Supply Voltage	V_{IN}	–1.0 to 12	V
$\overline{\text{Reset}}$ Output Voltage	V_O	–1.0 to 12	V
$\overline{\text{Reset}}$ Output Sink Current	I_{Sink}	Internally Limited	mA
Clamp Diode Forward Current, Pin 1 to 2 (Note 1)	I_F	100	mA
Power Dissipation and Thermal Characteristics			
P Suffix, Plastic Package			
Maximum Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	700	mW
Thermal Resistance, Junction-to–Air	$R_{\theta JA}$	178	$^\circ\text{C/W}$
D Suffix, Plastic Package			
Maximum Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	700	mW
Thermal Resistance, Junction-to–Air	$R_{\theta JA}$	178	$^\circ\text{C/W}$
DM Suffix, Plastic Package			
Maximum Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	520	mW
Thermal Resistance, Junction-to–Air	$R_{\theta JA}$	240	$^\circ\text{C/W}$
Operating Junction Temperature	T_J	+150	$^\circ\text{C}$
Operating Ambient Temperature Range	T_A		$^\circ\text{C}$
MC34164 Series		0 to +70	
MC33164 Series		– 40 to +125	
Storage Temperature Range	T_{stg}	– 65 to +150	$^\circ\text{C}$

NOTE: ESD data available upon request.

MC34164–3, MC33164–3 SERIES

ELECTRICAL CHARACTERISTICS (For typical values $T_A = 25^\circ\text{C}$, for min/max values T_A is the operating ambient temperature range that applies [Notes 2 & 3], unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
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COMPARATOR

Threshold Voltage					V
High State Output (V_{IN} Increasing)	V_{IH}	2.55	2.71	2.80	
Low State Output (V_{IN} Decreasing)	V_{IL}	2.55	2.65	2.80	
Hysteresis ($I_{\text{Sink}} = 100\ \mu\text{A}$)	V_H	0.03	0.06	–	

RESET OUTPUT

Output Sink Saturation ($V_{IN} = 2.4\ \text{V}$, $I_{\text{Sink}} = 1.0\ \text{mA}$) ($V_{IN} = 1.0\ \text{V}$, $I_{\text{Sink}} = 0.25\ \text{mA}$)	V_{OL}	– –	0.14 0.1	0.4 0.3	V
Output Sink Current (V_{IN} , $\overline{\text{Reset}} = 2.4\ \text{V}$)	I_{Sink}	6.0	12	30	mA
Output Off–State Leakage (V_{IN} , $\overline{\text{Reset}} = 3.0\ \text{V}$) (V_{IN} , $\overline{\text{Reset}} = 10\ \text{V}$)	$I_R(\text{leak})$	– –	0.02 0.02	0.5 1.0	μA
Clamp Diode Forward Voltage, Pin 1 to 2 ($I_F = 5.0\ \text{mA}$)	V_F	6.0	0.9	1.2	V

TOTAL DEVICE

Operating Input Voltage Range	V_{IN}	1.0 to 10	–	–	V
Quiescent Input Current $V_{IN} = 3.0\ \text{V}$ $V_{IN} = 6.0\ \text{V}$	I_{IN}	– –	9.0 24	15 40	μA

- Maximum package power dissipation limits must be observed.
- Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient as possible.
- $T_{\text{low}} = 0^\circ\text{C}$ for MC34164 $T_{\text{high}} = +70^\circ\text{C}$ for MC34164
 = -40°C for MC33164 = $+125^\circ\text{C}$ for MC33164

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MC34164–5, MC33164–5 SERIES

ELECTRICAL CHARACTERISTICS (For typical values $T_A = 25^\circ\text{C}$, for min/max values T_A is the operating ambient temperature range that applies [Notes 5 & 6], unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
COMPARATOR					
Threshold Voltage					V
High State Output (V_{in} Increasing)	V_{IH}	4.15	4.33	4.45	
Low State Output (V_{in} Decreasing)	V_{IL}	4.15	4.27	4.45	
Hysteresis ($I_{Sink} = 100\ \mu\text{A}$)	V_H	0.02	0.09	–	
RESET OUTPUT					
Output Sink Saturation ($V_{in} = 4.0\ \text{V}$, $I_{Sink} = 1.0\ \text{mA}$) ($V_{in} = 1.0\ \text{V}$, $I_{Sink} = 0.25\ \text{mA}$)	V_{OL}	– –	0.14 0.1	0.4 0.3	V
Output Sink Current (V_{in} , $\overline{\text{Reset}} = 4.0\ \text{V}$)	I_{Sink}	7.0	20	50	mA
Output Off-State Leakage (V_{in} , $\overline{\text{Reset}} = 5.0\ \text{V}$) (V_{in} , $\overline{\text{Reset}} = 10\ \text{V}$)	$I_R(\text{leak})$	– –	0.02 0.02	0.5 2.0	μA
Clamp Diode Forward Voltage, Pin 1 to 2 ($I_F = 5.0\ \text{mA}$)	V_F	0.6	0.9	1.2	V
TOTAL DEVICE					
Operating Input Voltage Range	V_{in}	1.0 to 10	–	–	V
Quiescent Input Current $V_{in} = 5.0\ \text{V}$ $V_{in} = 10\ \text{V}$	I_{in}	– –	12 32	20 50	μA

- Maximum package power dissipation limits must be observed.
- Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient as possible.
- $T_{low} = 0^\circ\text{C}$ for MC34164 $T_{high} = +70^\circ\text{C}$ for MC34164
 $\quad\quad\quad = -40^\circ\text{C}$ for MC33164 $\quad\quad\quad = +125^\circ\text{C}$ for MC33164

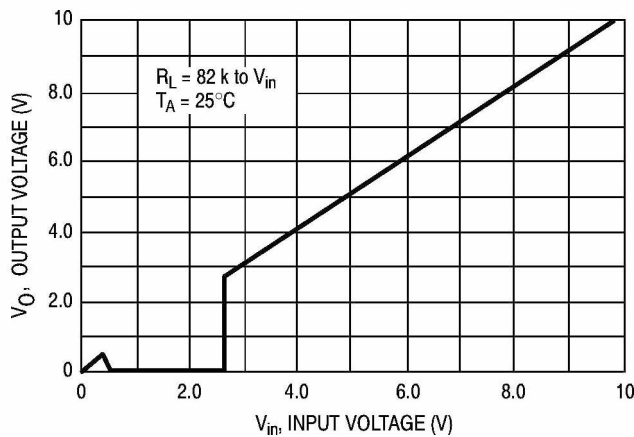


Figure 1. MC3X164–3 $\overline{\text{Reset}}$ Output Voltage versus Input Voltage

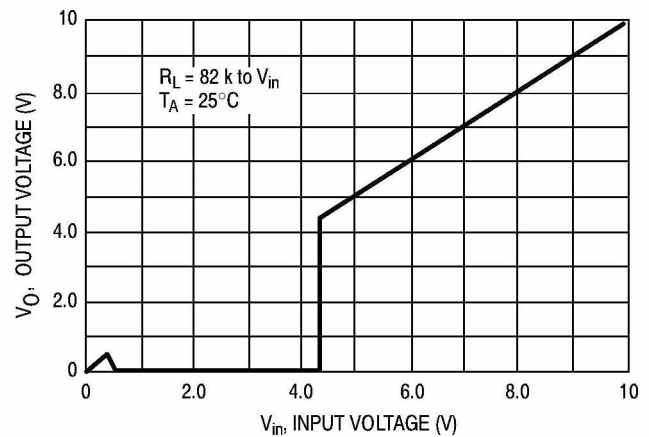


Figure 2. MC3X164–5 $\overline{\text{Reset}}$ Output Voltage versus Input Voltage

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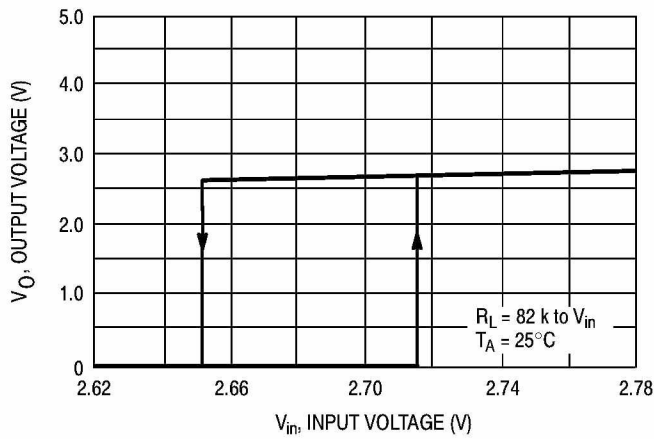


Figure 3. MC3X164-3 $\overline{\text{Reset}}$ Output Voltage versus Input Voltage

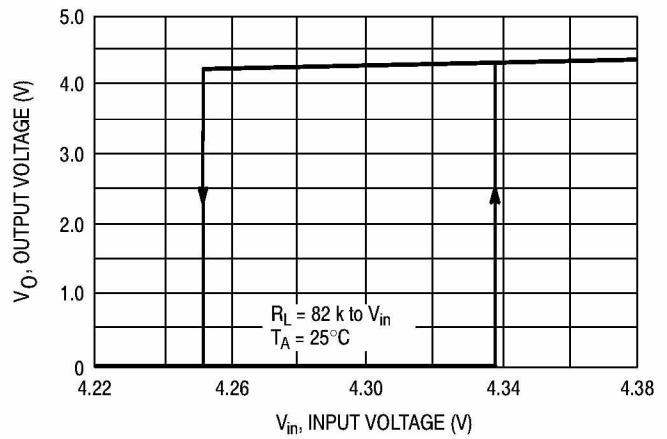


Figure 4. MC3X164-5 $\overline{\text{Reset}}$ Output Voltage versus Input Voltage

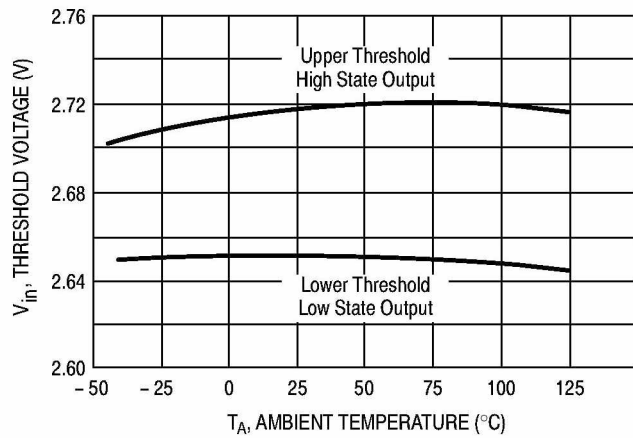


Figure 5. MC3X164-3 Comparator Threshold Voltage versus Temperature

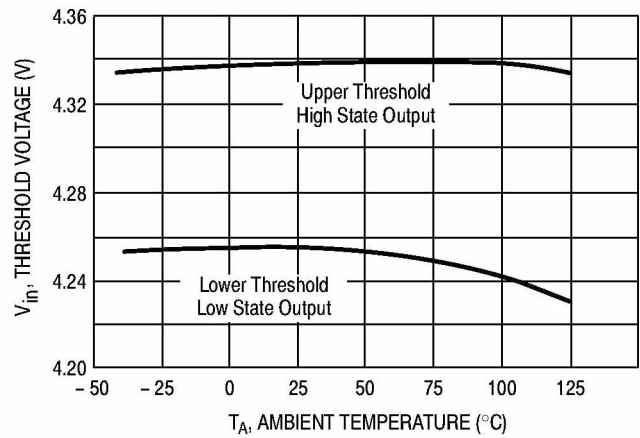


Figure 6. MC3X164-5 Comparator Threshold Voltage versus Temperature

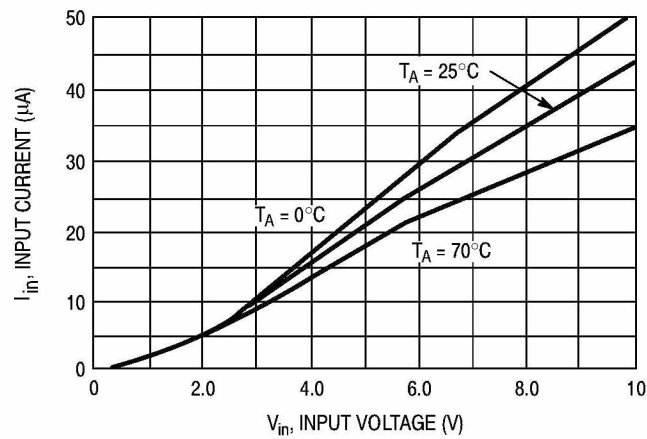


Figure 7. MC3X164-3 Input Current versus Input Voltage

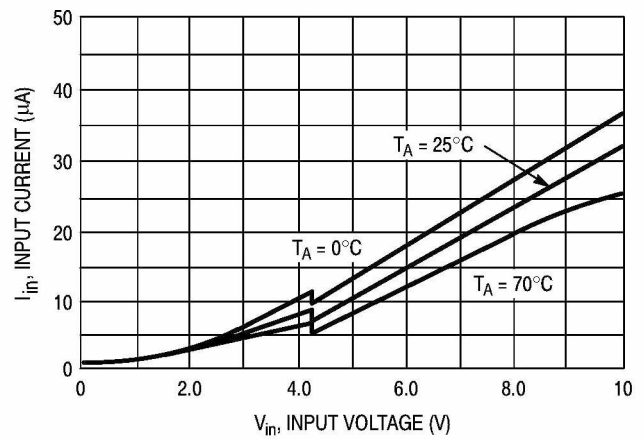


Figure 8. MC3X164-5 Input Current versus Input Voltage

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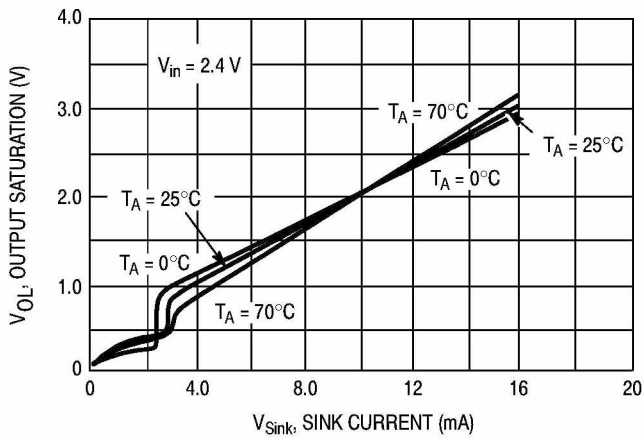


Figure 9. MC3X164-3 $\overline{\text{Reset}}$ Output Saturation versus Sink Current

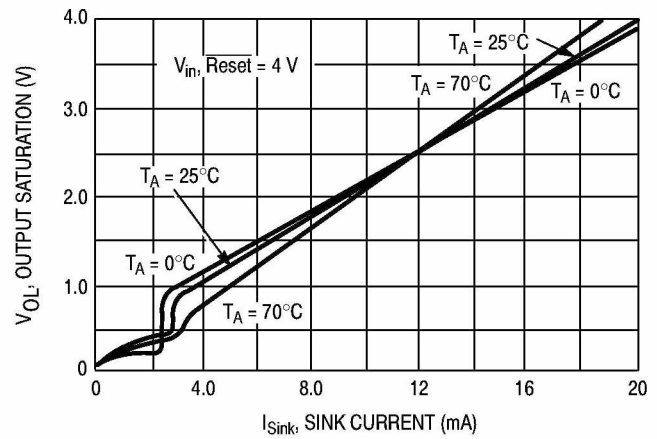


Figure 10. MC3X164-5 $\overline{\text{Reset}}$ Output Saturation versus Sink Current

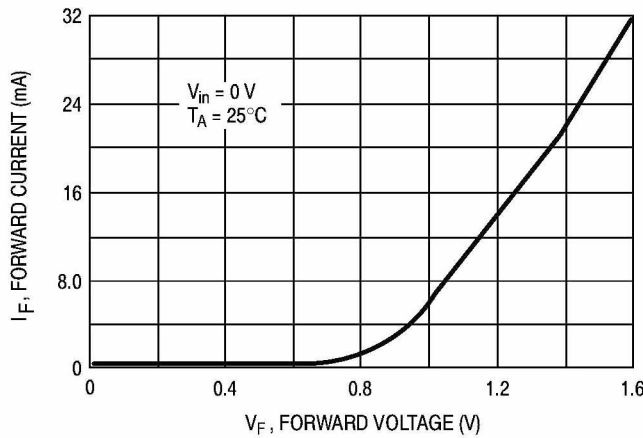


Figure 11. Clamp Diode Forward Current versus Voltage

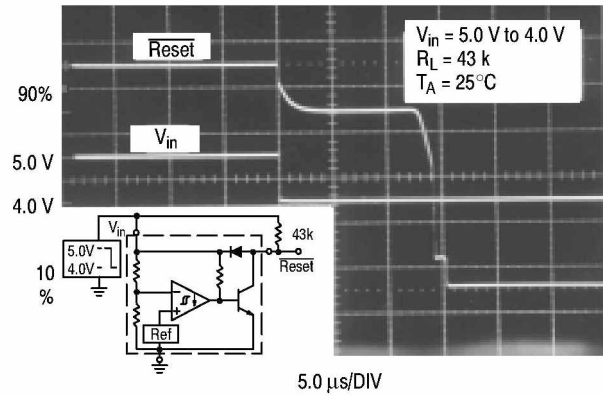
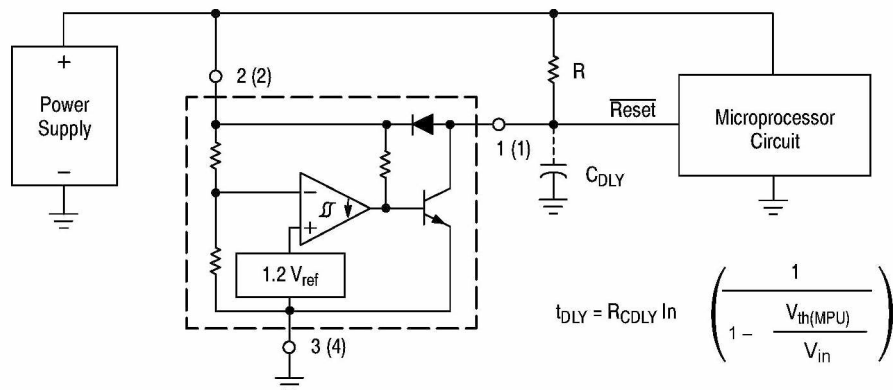


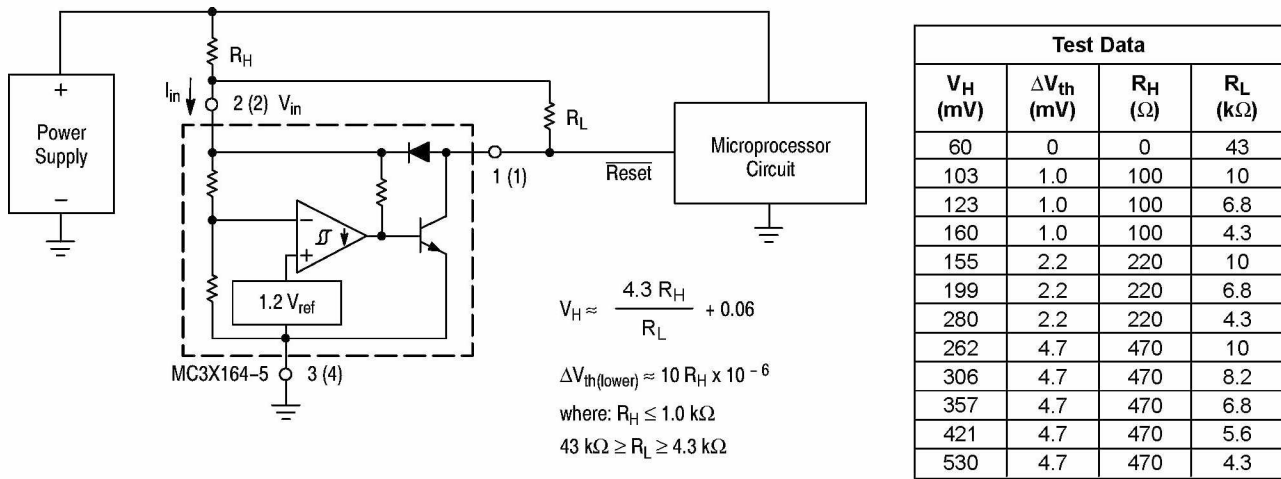
Figure 12. $\overline{\text{Reset}}$ Delay Time (MC3X164-5 Shown)



A time delayed reset can be accomplished with the addition of C_{DLY} . For systems with extremely fast power supply rise times (< 500 ns) it is recommended that the $R_{C_{DLY}}$ time constant be greater than $5.0 \mu\text{s}$. $V_{th(MPU)}$ is the microprocessor reset input threshold.

Figure 13. Low Voltage Microprocessor Reset

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Comparator hysteresis can be increased with the addition of resistor R_H . The hysteresis equation has been simplified and does not account for the change of input current I_{in} as V_{in} crosses the comparator threshold (Figure 8). An increase of the lower threshold $\Delta V_{th(lower)}$ will be observed due to I_{in} which is typically $10 \mu A$ at $4.3 V$. The equations are accurate to $\pm 10\%$ with R_H less than $1.0 k\Omega$ and R_L between $4.3 k\Omega$ and $43 k\Omega$.

Figure 14. Low Voltage Microprocessor Reset With Additional Hysteresis (MC3X164-5 Shown)

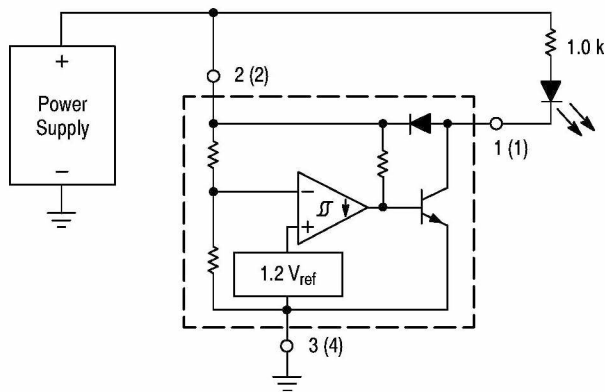


Figure 15. Voltage Monitor

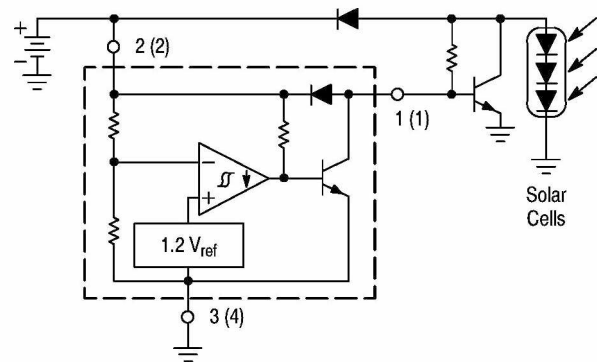


Figure 16. Solar Powered Battery Charger

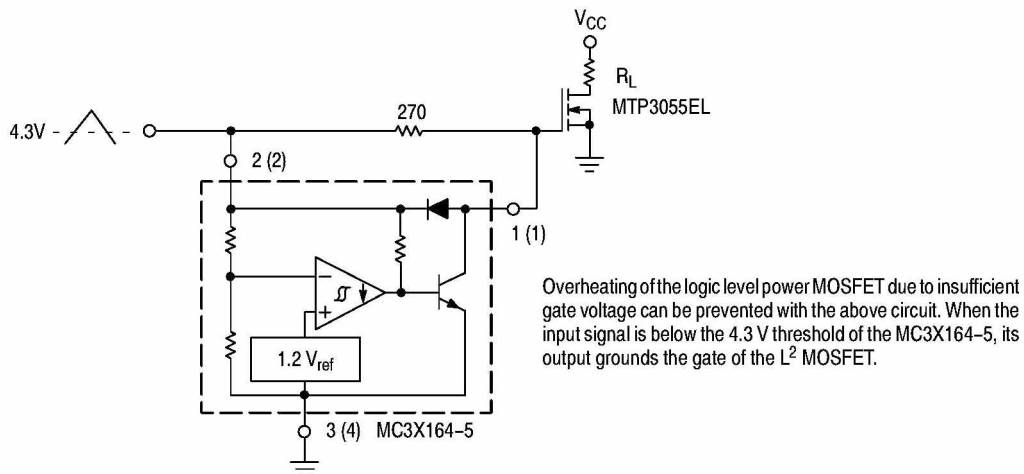


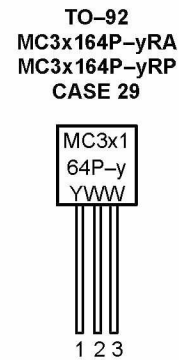
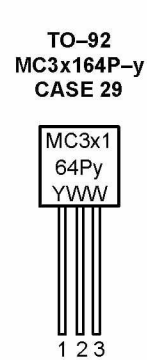
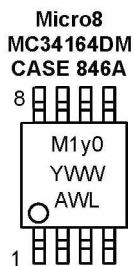
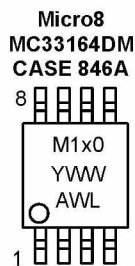
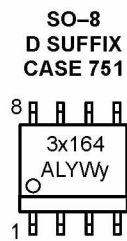
Figure 17. MOSFET Low Voltage Gate Drive Protection Using the MC3X164-5

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ORDERING INFORMATION

Device	Package	Shipping
MC33164D-3	SO-8	98 Units / Rail
MC33164D-3R2	SO-8	2500 Units / Tape & Reel
MC33164DM-3R2	Micro8	4000 Units / Tape & Reel
MC33164P-3	TO-92	2000 Units / Box
MC33164P-3RA	TO-92	2000 Units / Tape & Reel
MC33164P-3RP	TO-92	2000 Units / Pack
MC33164D-5	SO-8	98 Units / Rail
MC33164D-5R2	SO-8	2500 Units / Tape & Reel
MC33164DM-5R2	Micro8	4000 Units / Tape & Reel
MC33164P-5	TO-92	2000 Units / Box
MC33164P-5RA	TO-92	2000 Units / Tape & Reel
MC33164P-5RP	TO-92	2000 Units / Pack
MC34164D-3	SO-8	98 Units / Rail
MC34164D-3R2	SO-8	2500 Units / Tape & Reel
MC34164DM-3R2	Micro8	4000 Units / Tape & Reel
MC334164P-3	TO-92	2000 Units / Box
MC34164P-3RP	TO-92	2000 Units / Pack
MC34164D-5	SO-8	98 Units / Rail
MC34164D-5R2	SO-8	2500 Units / Tape & Reel
MC34164DM-5R2	Micro8	4000 Units / Tape & Reel
MC334164P-5	TO-92	2000 Units / Box
MC34164P-5RA	TO-92	2000 Units / Tape & Reel
MC34164P-5RP	TO-92	2000 Units / Pack

MARKING DIAGRAMS



x = Device Number 3 or 4
y = Suffix Number 3 or 5
A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week